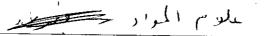
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	TANTA UNIVERSITY FACULTY OF SCIENCE DEPARTMENT OF PHYSICS			
		Physics & Material Science: (LEVELFOUR)		
COURSE TITLE:		tectors & Accelerators	COURSE CODE: PH4163	
TOTAL MARKS 100	SEMESTER: ONE	TIME ALLOWED: TWO HOURS	DATE: 27/12/2016	
a- Good spectrometer she b- Geiger Muller counter c- Ge(Li) detectors are m radiation d- Pair production cross s e- One advantage of lines Q2: A- Compare between tranyour answer (with necess	ould has high reso operates at relati fore suitable than section is proporti ar accelerators is a insverse and longitions sary figures and n	vely high voltage silicon detector for the detection of silicon detector for the detection of silicon detector for the detection of siliconal to Z ⁴ of the absorber that they emit synchrotron radiation tudinal Beta-particles magnetic specifical equations)	[15 Marks] () () of electromagnetic () () on () [23 Marks] electrometer, support (16 Marks)	
B- 1 cm thick lead absorwhat is total cross-section gm/cm ³ ?	ber attenuated ar	a initial 10 MeV neutron beam to atomic weight of Pb = 207.21 and	84.5% of its value, d its density is 11.3 (7 Marks)	
O3: Complete the follow 1- Slow neutrons are class a b 2- The different methods	sified into:	[42 Marks, 1.5 ma		
a b 3- Examples of solid state a b 4- Examples of gas filled	detectors are: detectors are:	c d	•••••	
a b- 5- Application of linear ac a b- 6- The advantages of circu	celerators are:ular accelerator o	cver linear accelerator are:		
a7- A linear particle accele	rator consists of t	bhe following elements:		
d 8- The disadvantages of ca	e ircular accelerato	····· f-	••••••	
	********	0	*************	
aetector		d basic principle of operation for port your answer with necessary f	(10 Marks)	
Examiner Pro	of. Dr. Mohsen Ell پانتوفيق ©	khosht © طيب التمنيات نكم بالنجاح و	r. Sherief Hamada.	





TANTA UNIVERSITY FACULTY OF SCIENCE DEPARTMENT OF PHYSICS

EXAMINATION FOR SENIORS (FOURTH YEAR) STUDENTS OF MATERIAL SCIENCE

COURSE TITLE: ELECTRON MICROSCOPY

COURSE CODE: MS4123

DATE:

TOTAL ASSESSMENT MARKS:100

TIME ALLOWED: 2 HOURS

ANSWER THE FOLLOWING QUESTIONS:

Q1 (25 Marks)

Write about:

a) Advantages and disadvantages of the transmission electron microscope.

(10 Marks)

b) Two methods of specimen preparation in TEM.

(10 Marks)

c) Spherical aberration in electron microscopy.

(5 Marks)

Q2 (25 Marks)

- a) Vacuum is nothing but everything in electron microscopy, Explain. (5 Marks)
- b) Summarize in a simple schematic the secondary effects that maybe detected when a primary electron beam interacts with a specimen. . (10 Marks)
- c) Write about X-ray energy dispersive spectroscopy XEDS. (10 Marks)

Q3 (20 Marks)

- a) Write about specimen preparation in SEM and the problems associated with non-conducting materials. (10 Marks)
- b) What are the differences between light microscopy and electron microscopy?

(<u>10 Marks</u>)

Q4- Choose the correct answer

(30 Marks, 3 marks each)

- 1- In electron optics, the device that corrects for astigmatism is called:
 - A) A stigmator
 - B) An electrostatic lens
 - C) A condenser lens
 - D) An electron probe
- 2- All of the following are true about field emission except:
 - A) The emitted electrons have very well defined energies.
 - B) Thermal excitation is not required
 - C) Evaporation from the surface that takes place during operation shortens the tip's lifetime.
 - D) Field emission requires a very high vacuum to achieve a stable operation.

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TANTA UNIVERSITY FACULTY OF SCIENCE DEPARTMENT OF PHYSICS

EXAMINATION FOR SENIORS (FORTH LEVEL) STUDENTS OF MATERIAL SCIENCE (SEMESTER 1)

COURSE TITLE:

INTRODUCTION TO NANO-TECHNOLOGY

COURSE CODE: MS4163

DECMBER 2016 | TERM: SUMMER

TOTAL ASSESSMENT MARKS: 100

TIME ALLOWED: 2 HOURS

Answer The Following:

First question:

{25 Marks} (12 Marks)

A) Define the following:

1) Nanomaterials. 2- Bulk materials. 3- Grain size. 4- Crystallite size.

B) What are the advantages and the hazard of using (nanomaterials comparing to bulk (13 Marks) materials) nanotechnology and microtechnology.

Second question:

{25 Marks}

- (10 Marks) A) Write short notes on the following: The unique size-dependent properties of nanomaterial "magnetic, electrical, physical, ..." (give examples).
- B) Discuss the fabrication methods (top down-bottom up) of the nanomaterials; (give an (15 Marks) example), declare your answer by drawing.

Third question:

{20 Marks}

- A) Discuss briefly the methods for characterization of nanomaterials "XRD, SEM, TEM,..." (10 Marks)
- B) Discuss the application of nanomaterials in (Information and communications).

(10 Marks)

Fourth question:

{30 Marks}

Discuss and show the advantage of using nanotechnology of the following fields:

a) Diseases Diagnostic.

(10 Marks)

b) Environment.

(10 Marks)

c) REAEWEBLE ENERGY

(10 Marks)

Examiners	Prof. Talaat M. Meaz	Prof. Samia A. Saafan

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		TANTA UNIVERS	NTA UNIVERSITY- Faculty of Science -Department of Physics		
			R SENIORS STUDENTS OF BIOPHYS		
7.5	COURSE TITLE:		Physical Electronics	COURSE CODE: PH4113	
DATE:	1STJANUARY- 2017	TERM: FIRST	TOTAL ASSESSMENT MARKS: 100	TIME ALLOWED: 2 HOURS	

Answer the following questions:

1- Define shortly:

(25 marks)

- a- monocrystalline, amorphous and polycrystalline solids
- b- fractional distillation technique
- c- Czochralsky method
- 2- a- Summarize the steps of manufacturing Si wafers.

(10 marks)

- b- Draw a figure showing the coulombic potential wells of two atoms close to each other, along with the wave functions of two electrons centered on the two nuclei. And show how for such an interacting system two-electron wave functions are probable and what happens if many atoms that are brought together?
- 3- a-Si and GaAs have indirect and direct energy gaps and this is affecting their use in practical devices. Illustrate this statement clarifying your answer with simple drawings. (15 marks)
 - b- Define donor levels and acceptor levels in extrinsic semiconductors. (10 marks)
- 4- a- Deduce the total current due to both drift and diffusion of n and p charge carriers in a semiconductor. (15 marks)
 - b- Define "excess" carriers and how they can be created?

(5 marks)

c- Define luminescence and its classification to three types depending on how the excess carriers are generated. (5 marks)

EXAMINER

PROF. DR. SAMIA AHMED SAAFAN

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Marie Comment	<u> </u>	TANTA UNIVERSITY- Faculty of Science -Department of Physics				
-		EXAM FOR SENIORS STUDENTS OF MATERIALS SCIENCE				
i III i c	COURSE TITLE	Materials Design	COURSE CODE:MS4121			
DATE:	5-1-2017	TERM: FIRST TOTAL ASSESSMENT MARKS: 100	TIME ALLOWED: 2 HOURS			

First Question:

i) Cite the criteria that are important in the **Selection consideration** of materials.

[10Marks]

II) Using the selection consideration developed for minimum material mass and <u>minimum cost</u>, describe the acceptable candidates from the following Five Engineering Materials. [10Marks]

Material	$(Me\ell m^3)$	$\frac{ au_f}{(MPa)}$	Ē (SIS)
Carbon fiber-reinforced composite(CF-RC)	1.5	1140	80
Glass fiber-reinforced composite(GFRC)	2.0	1060	40
Aluminum alloy (2024-T6)(Al.A)	2.8	300	15
Titanium alloy (Ti-6Al-4V)(Ti-AL.A)	4.4	525	
4340 Steel.	7.8	780	

Density (p), Strength (τ_f), and Relative Cost(i-) for Five Engineering Materials.

Second Question:

- I) Find the <u>shear stress</u> of a helical spring has been constructed of wire having a circular cross section diameter (d), the coil center to center diameter (D), a compressive force (F) and force independent constant $k_w = 1 + \frac{1}{2C}$.
- II) Prove that the Stiffness of spring is $\left(\frac{G \cdot d}{8n \cdot C^3}\right)$. Where (G) and (C) are the rigidity and spring constant of coil material.

Third Question:

- List and briefly explain the <u>biocompatibility</u> considerations relative to materials that are employed in artificial hip replacements.
- II) Compare between the specific properties of the three materials are employed in the <u>femoral stem</u> of the artificial hip replacement. [15Marks]

Forth Question:

I) Write the Required mechanical properties of the hip joint replaced components.

[10Marks]

II) List the Requirements of the <u>Thermal Protection System Design</u> on the Space Shuttle Orbiter.

[10Marks]

III) Write short notes about reinforced carbon-carbon used in the Designof Space Shuttle Orbiter.

[10Marks]

EXAMINER DR. REDA EL-SHATER

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